

2SC4512

Silicon NPN Triple Diffused Planar Transistor (Complement to type 2SA1726)

Application : Audio and General Purpose

Absolute maximum ratings (Ta=25°C)

Symbol	2SC4512	Unit
VCBO	120	V
VCEO	80	V
VEBO	6	V
IC	6	A
IB	3	A
PC	50(Tc=25°C)	W
Tj	150	°C
Tstg	-55 to +150	°C

Electrical Characteristics (Ta=25°C)

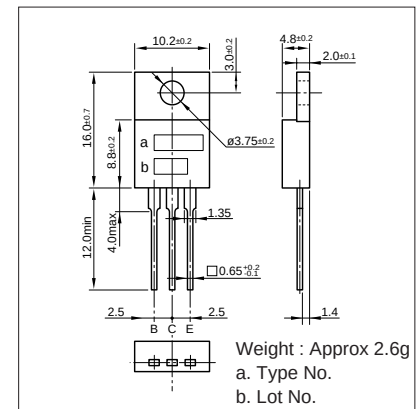
Symbol	Conditions	2SC4512	Unit
ICBO	VCB=120V	10max	μA
IEBO	VEB=6V	10max	μA
V(BR)CEO	IC=25mA	80min	V
hFE	VCE=4V, IC=2A	50min	
VCE(sat)	IC=5A, IB=0.2A	0.5max	V
fr	VCE=12V, IE=-0.5A	20typ	MHz
COB	VCB=10V, f=1MHz	110typ	pF

*hFE Rank $\bar{O}$ (50to100), P(70to140), Y(90to180)

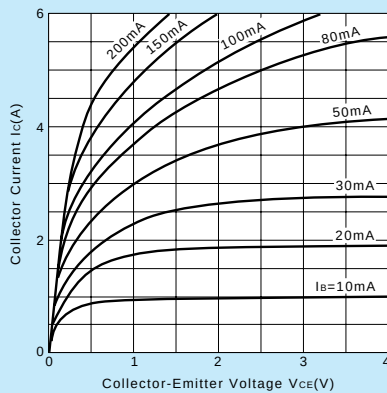
Typical Switching Characteristics (Common Emitter)

VCC (V)	RL (Ω)	IC (A)	VBB1 (V)	VBB2 (V)	IB1 (A)	IB2 (A)	ton (μs)	tstg (μs)	tf (μs)
30	10	3	10	-5	0.3	-0.3	0.16typ	2.60typ	0.34typ

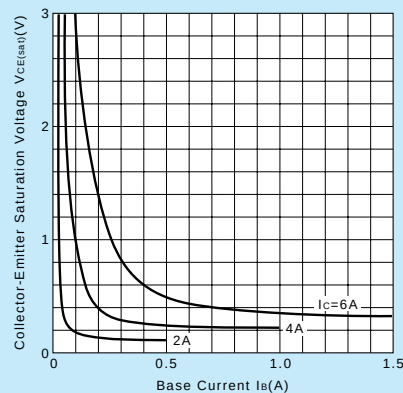
External Dimensions MT-25(TO220)



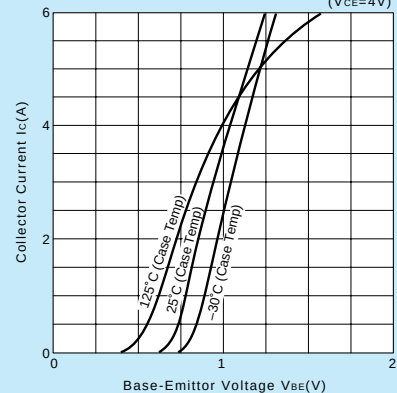
IC-VCE Characteristics (Typical)



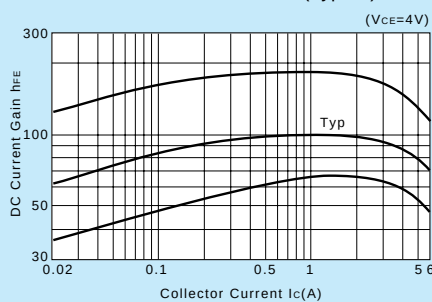
VCE(sat)-IB Characteristics (Typical)



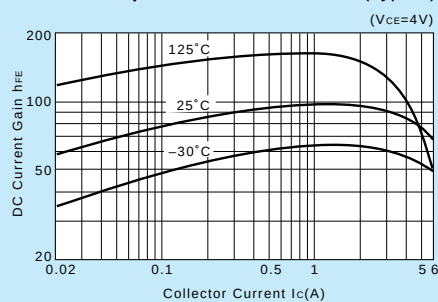
IC-VBE Temperature Characteristics (Typical)



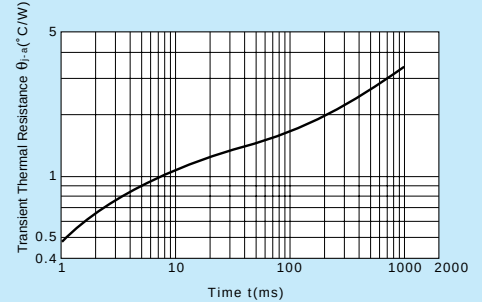
hFE-IC Characteristics (Typical)



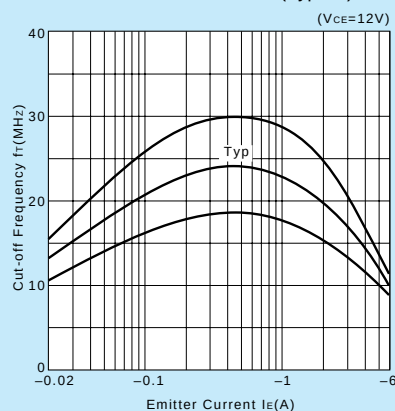
hFE-IC Temperature Characteristics (Typical)



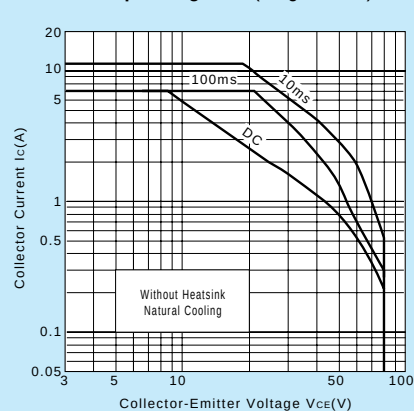
θj-a-t Characteristics



fr-IE Characteristics (Typical)



Safe Operating Area (Single Pulse)



PC-Ta Derating

